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PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

U.S. Patent No.: 6,943,369

Patented: September 13, 2005

Inventor: Hisao HAYASHI

For: SUBSTRATE FOR INTEGRATING AND
FORMING A THIN FILM SEMICONDUCTOR
DEVICE THEREON

LETTER CALLING ATTENTION TO ERRORS IN PATENT

Commissioner of Patents
Alexandria, VA 22313

Sir:

It is respectfully requested that this paper, calling attention to the following error(s) in this patent, be made of record in the patent file:

Column 8:

Lines 8 and 64, "A" should read -- An --.

Column 9:

Lines 1, 3, 5, and 9, "A" should read -- An--.

Column 10:

Lines 1 and 11, "A" should read -- An --.

Certificate

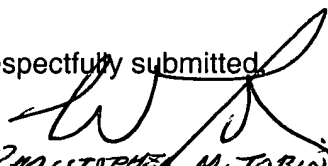
APR 26 2006

of Correction

Dated: March 30, 2006

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Respectfully submitted,


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